## INTEGRATED CIRCUITS

## DATA SHEET

# **74ABT20**Dual 4-input NAND gate

Product specification

1995 Sep 22

IC23 Data Handbook



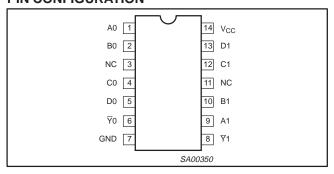
## **Dual 4-input NAND gate**

**74ABT20** 

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25^{\circ}C;$ $GND = 0V$	TYPICAL	UNIT
<sup>t</sup> PLH <sup>t</sup> PHL	Propagation delay An, Bn, Cn, Dn to Yn	C <sub>L</sub> = 50pF; V <sub>CC</sub> = 5V	2.7 2.2	ns
toslh toshl	Output to Output skew		0.3	ns
C <sub>IN</sub>	Input capacitance	V <sub>I</sub> = 0V or V <sub>CC</sub>	3	pF
I <sub>CC</sub>	Total supply current	Outputs disabled; V <sub>CC</sub> = 5.5V	50	μΑ

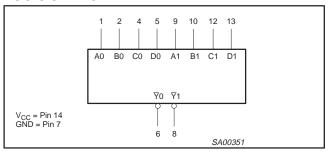
#### **PIN CONFIGURATION**



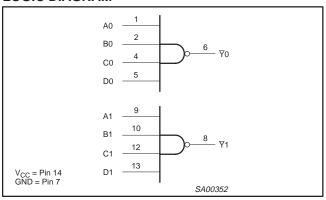
#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 4, 5, 9, 10, 12, 13	An, Bn, Cn, Dn	Data inputs
6, 8	₹n	Data outputs
7	GND	Ground (0V)
14	V <sub>CC</sub>	Positive supply voltage

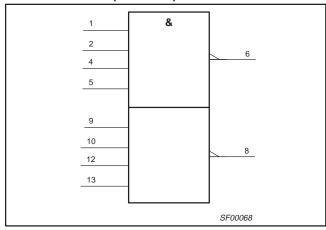
#### **LOGIC SYMBOL**



#### **LOGIC DIAGRAM**



#### LOGIC SYMBOL (IEEE/IEC)



#### **FUNCTION TABLE**

	INP	UTS		OUTPUT
An	Bn	Cn	Dn	₹n
L	Х	Х	Х	Н
Х	L	Х	Х	Н
Х	Х	L	Х	Н
Х	Х	Х	L	Н
Н	Н	Н	Н	L

#### NOTES:

H = High voltage level L = Low voltage level

X = Don't care

#### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic DIP	-40°C to +85°C	74ABT20 N	74ABT20 N	SOT27-1
14-Pin plastic SO	-40°C to +85°C	74ABT20 D	74ABT20 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +85°C	74ABT20 DB	74ABT20 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +85°C	74ABT20 PW	74ABT20PW DH	SOT402-1

## Dual 4-input NAND gate

74ABT20

#### **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	-18	mA
V <sub>I</sub>	DC input voltage <sup>3</sup>		-1.2 to +7.0	V
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0	<del>-</del> 50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	output in Off or High state	-0.5 to +5.5	V
I <sub>OUT</sub>	DC output current	output in Low state	40	mA
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C

#### NOTES

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
  device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
  absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- 3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	ITS	UNIT
STWIBOL	FARAMETER	MIN	MAX	ONIT
V <sub>CC</sub>	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V <sub>CC</sub>	V
V <sub>IH</sub>	High-level input voltage	2.0		V
V <sub>IL</sub>	Low-level input voltage		0.8	V
I <sub>OH</sub>	High-level output current		-15	mA
I <sub>OL</sub>	Low-level output current		20	mA
Δt/Δν	Input transition rise or fall rate	0	10	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

#### DC ELECTRICAL CHARACTERISTICS

				LIMITS							
SYMBOL	PARAMETER	TEST CONDITIONS	Ta	<sub>mb</sub> = +25	s°C	T <sub>amb</sub> =	: –40°C 85°C	UNIT			
			MIN	TYP	MAX	MIN	MAX	1			
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 4.5V; I_{IK} = -18mA$		-0.9	-1.2		-1.2	V			
V <sub>OH</sub>	High-level output voltage	$V_{CC} = 4.5V$ ; $I_{OH} = -15mA$ ; $V_I = V_{IL}$ or $V_{IH}$	2.5	2.9		2.5		V			
V <sub>OL</sub>	Low-level output voltage	$V_{CC} = 4.5V$ ; $I_{OL} = 20mA$ ; $V_I = V_{IL}$ or $V_{IH}$		0.35	0.5		0.5	V			
II	Input leakage current	$V_{CC} = 5.5V; V_I = GND \text{ or } 5.5V$		±0.01	±1.0		±1.0	μΑ			
I <sub>OFF</sub>	Power-off leakage current	$V_{CC} = 0.0V$ ; $V_O$ or $V_1 \le 4.5V$		±5.0	±100		±100	μΑ			
I <sub>CEX</sub>	Output High leakage current	$V_{CC} = 5.5V$ ; $V_O = 5.5V$ ; $V_I = GND$ or $V_{CC}$		5.0	50		50	μΑ			
Ιο	Output current <sup>1</sup>	$V_{CC} = 5.5V; V_O = 2.5V$	-50	-75	-180	-50	-180	mA			
I <sub>CC</sub>	Quiescent supply current	$V_{CC} = 5.5V$ ; $V_I = GND$ or $V_{CC}$		2	50		50	μΑ			
Δl <sub>CC</sub>	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 5.5V; One data input at 3.4V, other inputs at $V_{CC}$ or GND		0.25	500		500	μА			

#### NOTES:

- 1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
- 2. This is the increase in supply current for each input at 3.4V.
- 3. For valid test results, data must not be loaded into the flip-flop or latch after applying the power.

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## Dual 4-input NAND gate

74ABT20

#### **AC CHARACTERISTICS**

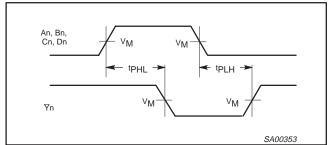
GND = 0V;  $t_R$  =  $t_F$  = 2.5ns;  $C_L$  = 50pF,  $R_L$  = 500 $\Omega$ 

SYMBOL	PARAMETER	WAVEFORM	T <sub>a</sub>	<sub>amb</sub> = +25° ' <sub>CC</sub> = +5.0'	C V	T <sub>amb</sub> = -40° V <sub>CC</sub> = +5.	UNIT	
			MIN	TYP	MAX	MIN	MAX	
t <sub>PLH</sub>	Propagation delay An, Bn, Cn, Dn to Yn	1	1.0 1.0	2.7 2.2	3.9 3.4	1.0 1.0	4.6 3.8	ns
toshl toshh1	Output to Output skew An or Bn to Yn	2		0.3	0.5		0.5	ns

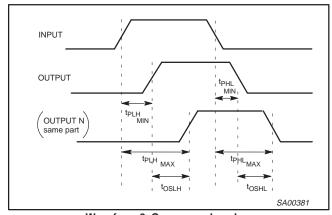
#### NOTE:

#### **AC WAVEFORMS**

 $V_M = 1.5V$ ,  $V_{IN} = GND$  to 3.0V

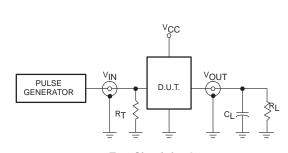


Waveform 1. Propagation Delay for Inverting Outputs



Waveform 2. Common edge skew

#### **TEST CIRCUIT AND WAVEFORMS**



**Test Circuit for Outputs** 

#### AMP (V) NEGATIVE $^{\text{V}}\text{M}$ PULSE 10% 10% tTHL (tF) tTLH (tR) tTHL (tF) tTLH (tR) AMP (V) **POSITIVE** PULSE 10% ΩV $V_{M} = 1.5V$

#### **Input Pulse Definition**

FAMILY	INPUT PULSE REQUIREMENTS											
	Amplitude	Rep. Rate	t <sub>W</sub>	t <sub>R</sub>	t <sub>F</sub>							
74ABT	3.0V	1MHz	500ns	2.5ns	2.5ns							

#### SH00067

#### **DEFINITIONS**

R<sub>L</sub> = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$  capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

R<sub>T</sub> = Termination resistance should be equal to Z<sub>OUT</sub> of pulse generators.

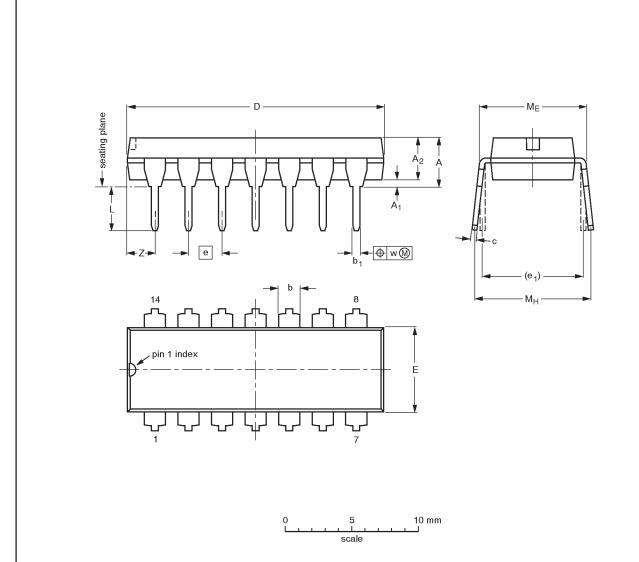
Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.

## Dual 4-input NAND gate

74ABT20

#### DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

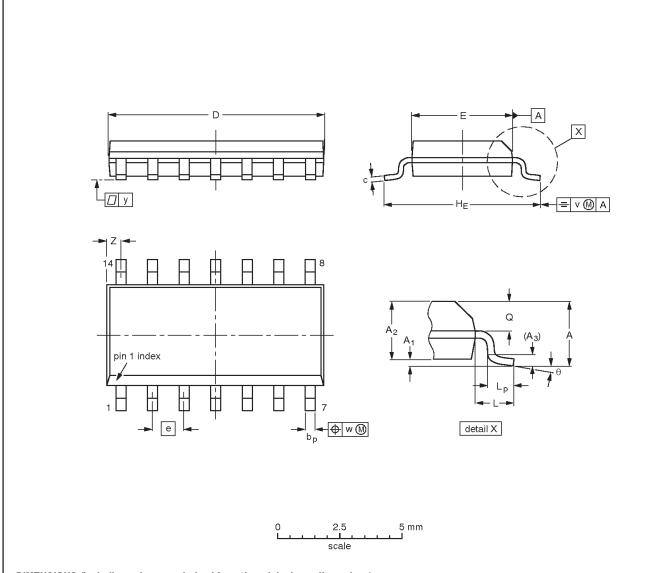
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT27-1	050G04	MO-001AA				<del>92-11-17</del> 95-03-11	

## Dual 4-input NAND gate

74ABT20

#### SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	А3	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.35 0.34	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

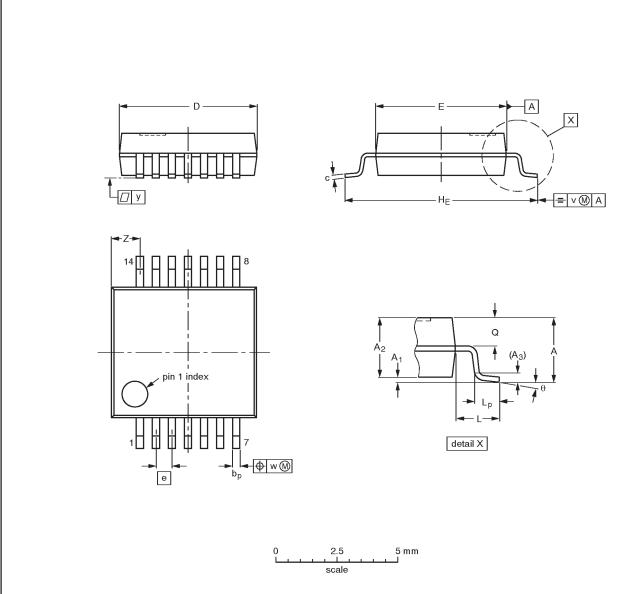
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VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT108-1	076E06S	MS-012AB				<del>95-01-23</del> 97-05-22	

## Dual 4-input NAND gate

74ABT20

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

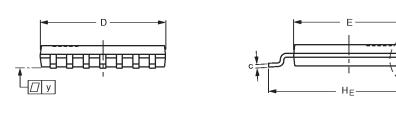
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1990E DATE	
SOT337-1		MO-150AB				<del>-95-02-04</del> 96-01-18	

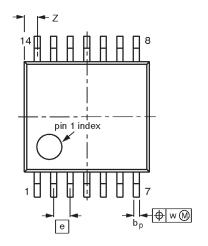
## Dual 4-input NAND gate

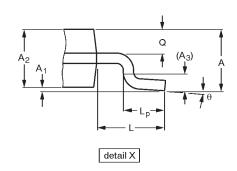
74ABT20

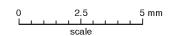
TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1









#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	bр	c	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	IEC JEDEC		PROJECTION	ISSUE DATE	١
SOT402-1		MO-153			<del>-94-07-12</del> 95-04-04	

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## Dual 4-input NAND gate

74ABT20

**NOTES** 

### Dual 4-input NAND gate

74ABT20

	DEFINITIONS							
Data Sheet Identification	Product Status	Definition						
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifical may change in any manner without notice.						
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. P Semiconductors reserves the right to make changes at any time without notice in order to improve de and supply the best possible product.						
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